

P85GC28HP2F

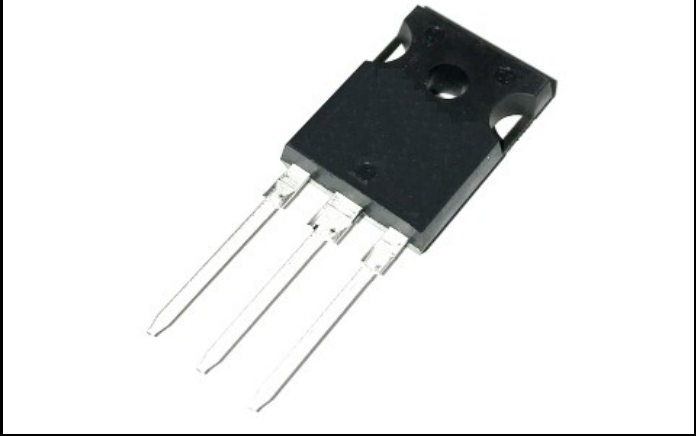
Power MOSFETs
280V, 85A, N-channel

Feature

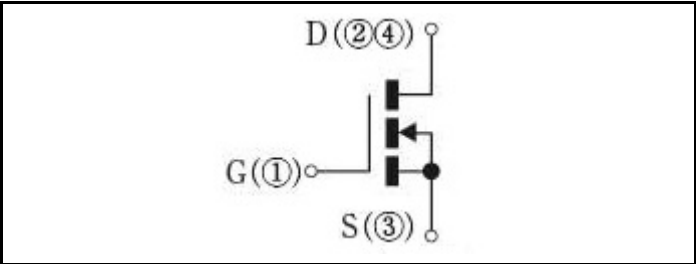
- N-channel
- High Voltage
- High Speed Switching
- Low Ron
- Low Capacitance
- Halogen free
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): GC
Package (JEDEC Code): TO-247AD



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel temperature	Tch		-55 to 150	°C
Drain-source voltage	V _{DSS}		280	V
Gate-source voltage	V _{GSS}		±30	V
Continuous drain current(DC)	I _D		85	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10μs, Duty=1/100	340	A
Continuous source current(DC)	I _S		85	A
Total power dissipation	P _T	With heatsink	430	W
Repetitive avalanche current	I _{AR}	Starting Tch=25°C Tch≤150°C	50	A
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≤150°C	240	mJ
Repetitive avalanche energy	E _{AR}	Starting Tch=25°C Tch≤150°C	24	mJ
Drain-source diode di/dt strength	di/dt	I _S =85A, Tc=25°C	350	A/μs
Mounting torque	TOR	(Recommended torque : 0.5N·m)	0.8	N·m

※ :See the original Specifications

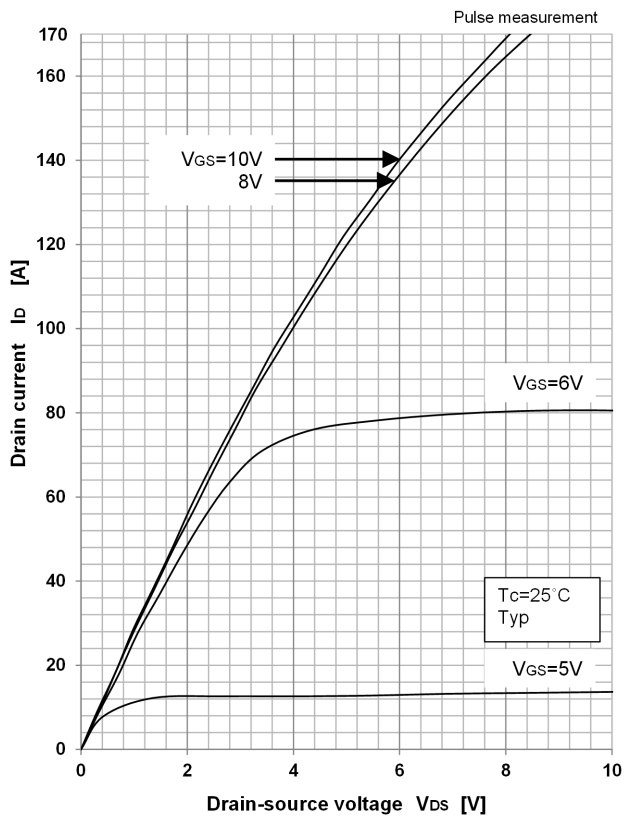
Electrical Characteristics (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	280			V
Zero gate voltage drain current	I_{DSS}	VDS=280V, VGS=0V			100	μA
Gate-source leakage current	I_{GSS}	VGS=±30V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=42.5A, VDS=10V	32.5	65		S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=42.5A, VGS=10V		0.035	0.045	Ω
Gate threshold voltage	V_{th}	ID=3mA, VDS=10V	2		4.5	V
Source-drain diode forward voltage	V_{SD}	IS=42.5A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case, with heatsink			0.29	°C/W
Total gate charge	Q_g	VDS=200V, VGS=10V, ID=85A		110		nC
Input capacitance	C_{iss}	VDS=50V, VGS=0V, f=1MHz		4375		pF
Reverse transfer capacitance	C_{rss}	VDS=50V, VGS=0V, f=1MHz		42		pF
Output capacitance	C_{oss}	VDS=50V, VGS=0V, f=1MHz		665		pF
Turn-on delay time	$t_{d(on)}$	ID=42.5A, RL=3.53Ω, VDS=150V, Rg=50Ω, +VGS=10V, -VGS=0V		100		ns
Rise time	t_r	ID=42.5A, RL=3.53Ω, VDS=150V, Rg=50Ω, +VGS=10V, -VGS=0V		246		ns
Turn-off delay time	$t_{d(off)}$	ID=42.5A, RL=3.53Ω, VDS=150V, Rg=50Ω, +VGS=10V, -VGS=0V		424		ns
Fall time	t_f	ID=42.5A, RL=3.53Ω, VDS=150V, Rg=50Ω, +VGS=10V, -VGS=0V		200		ns
Diode reverse recovery time	t_{rr}	IS=85A, VGS=0V, -di/dt=100A/μs		83		ns
Diode reverse recovery charge	Q_{rr}	IS=85A, VGS=0V, -di/dt=100A/μs		210		nC

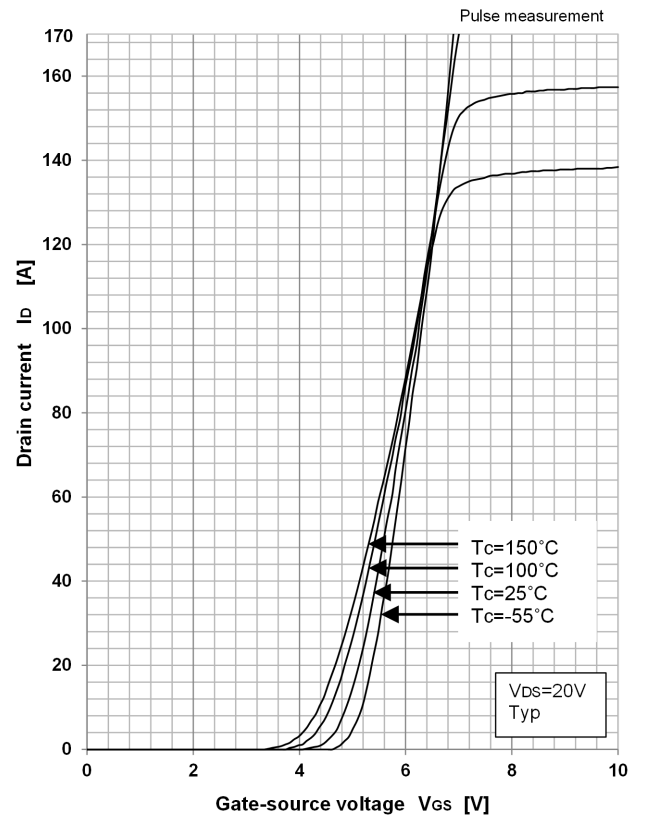
※ : See the original Specifications

CHARACTERISTIC DIAGRAMS

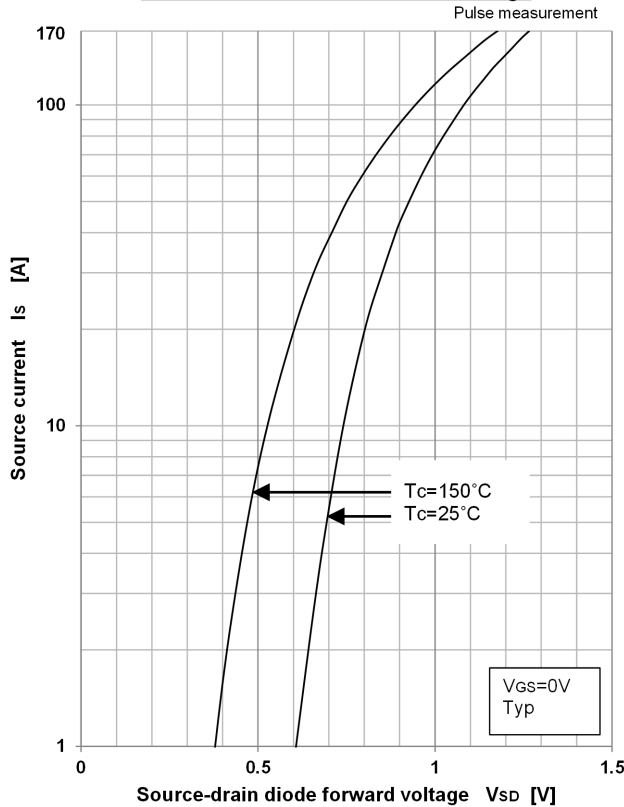
Typical output characteristics



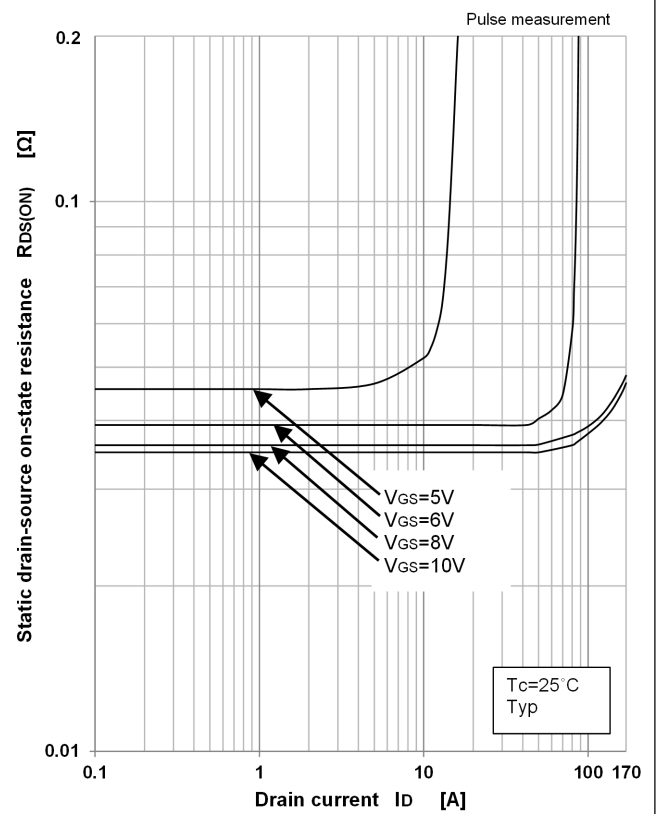
Transfer characteristics

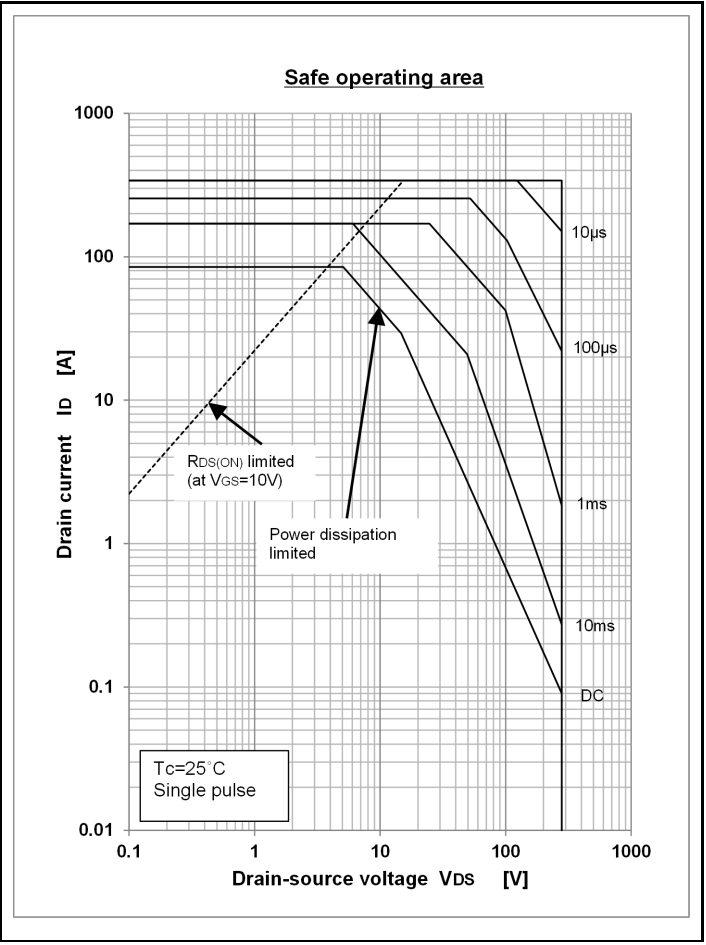
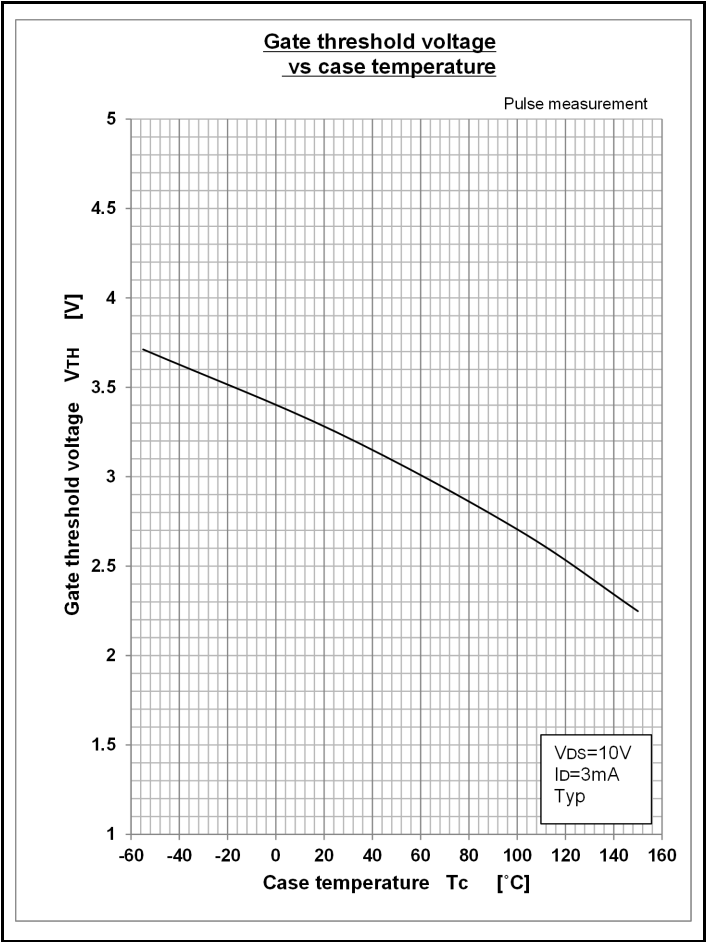
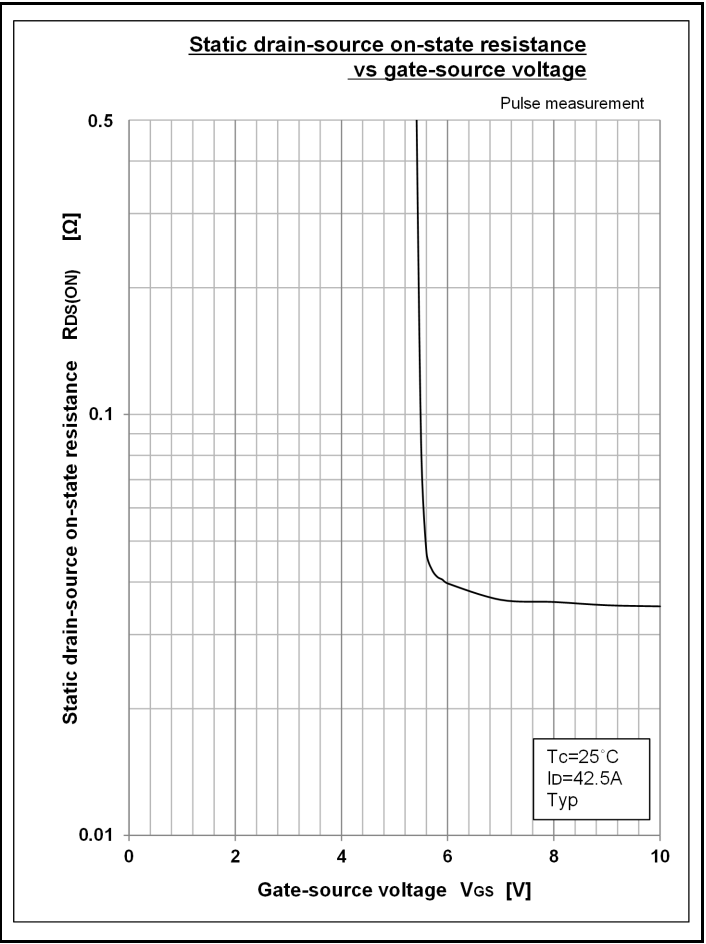
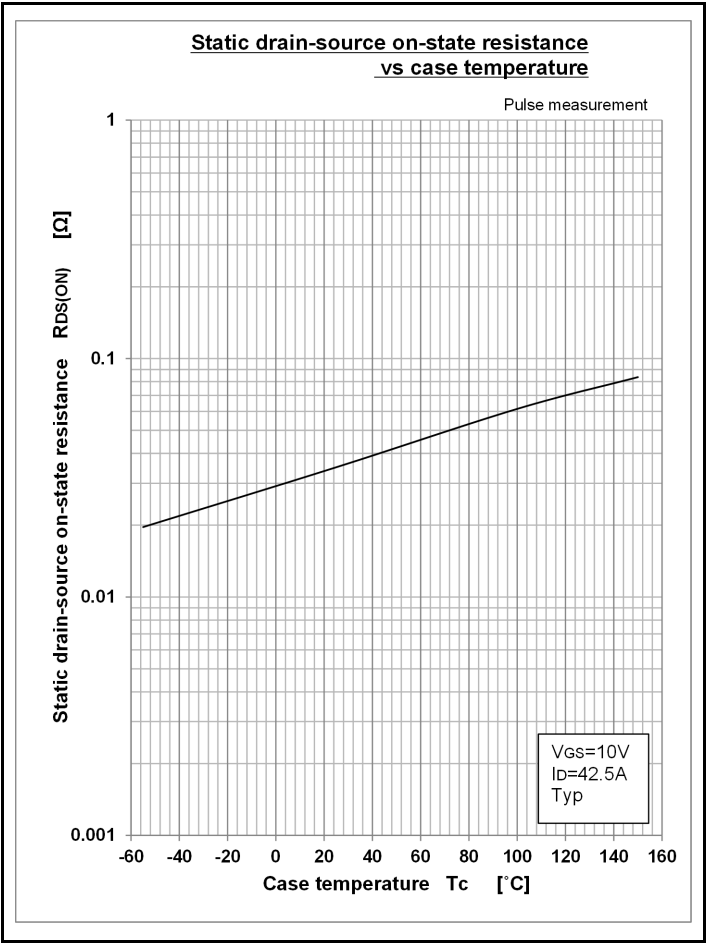


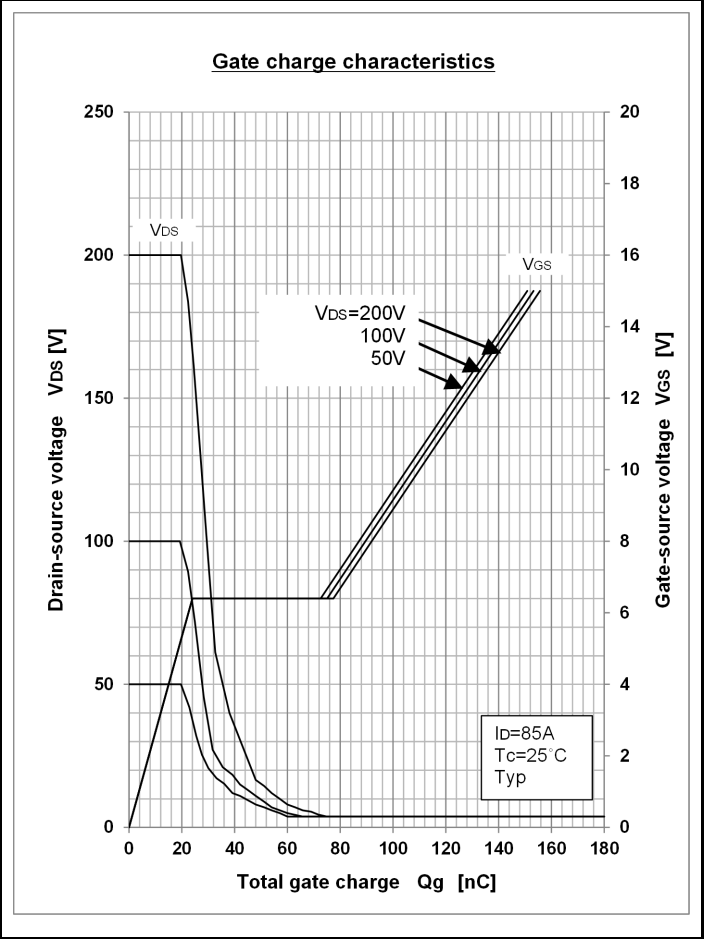
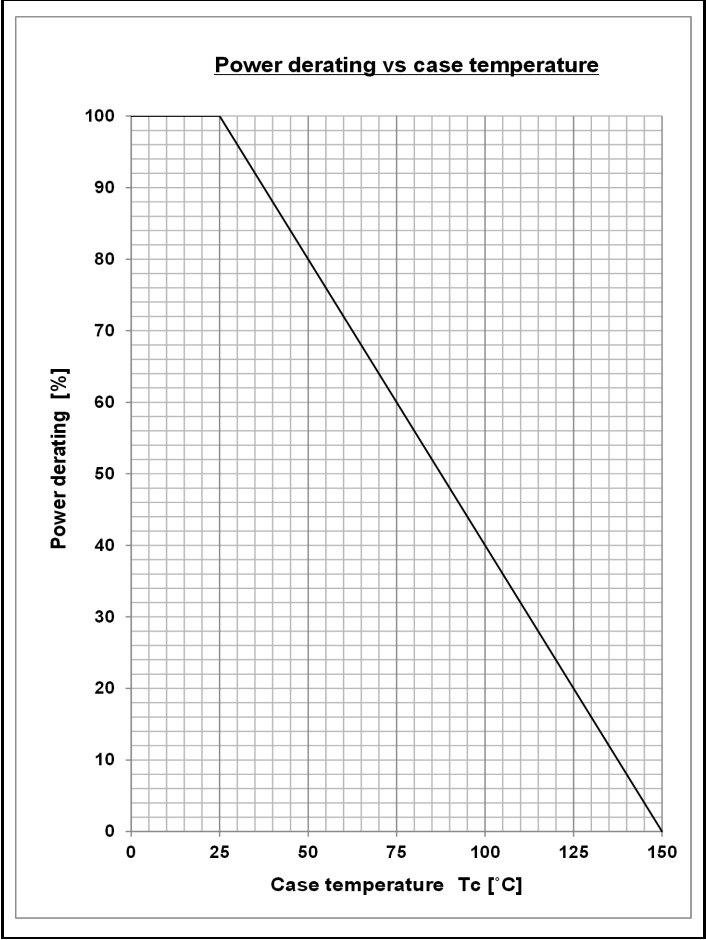
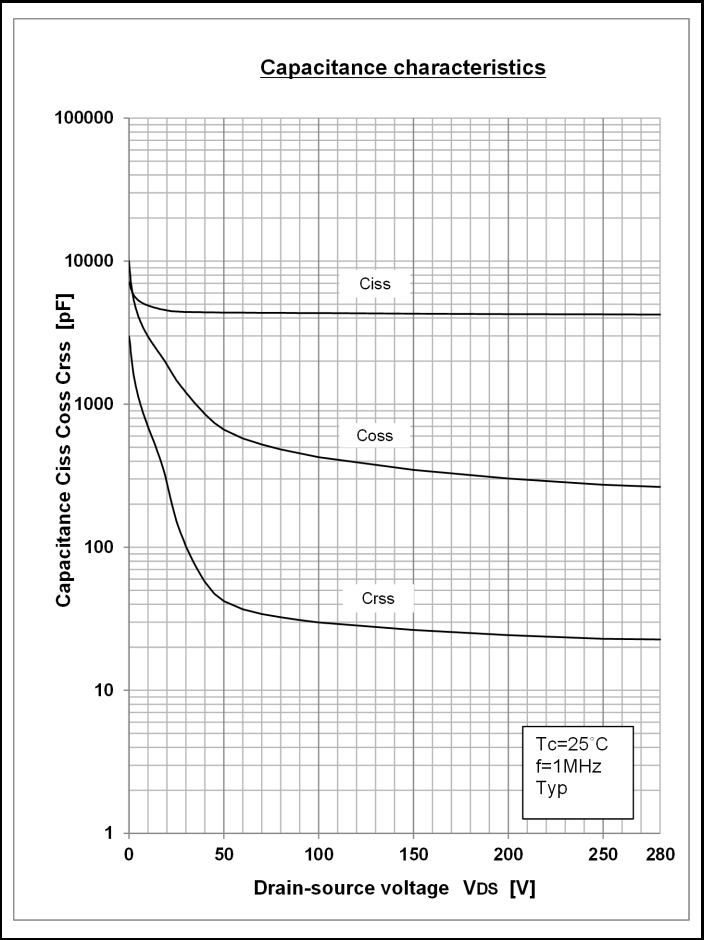
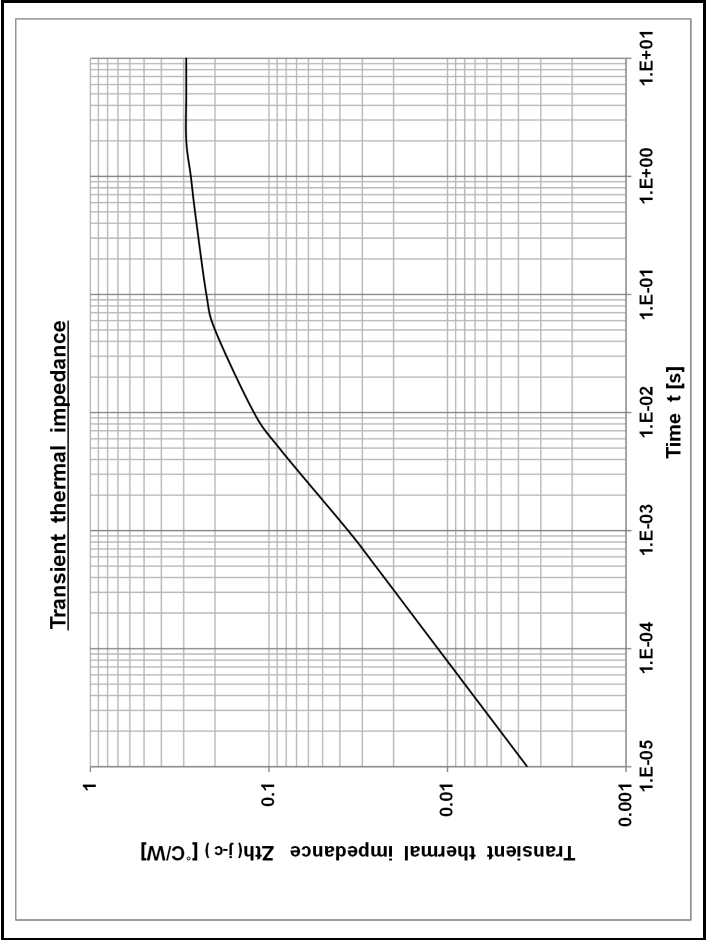
Source current vs source-drain diode forward voltage

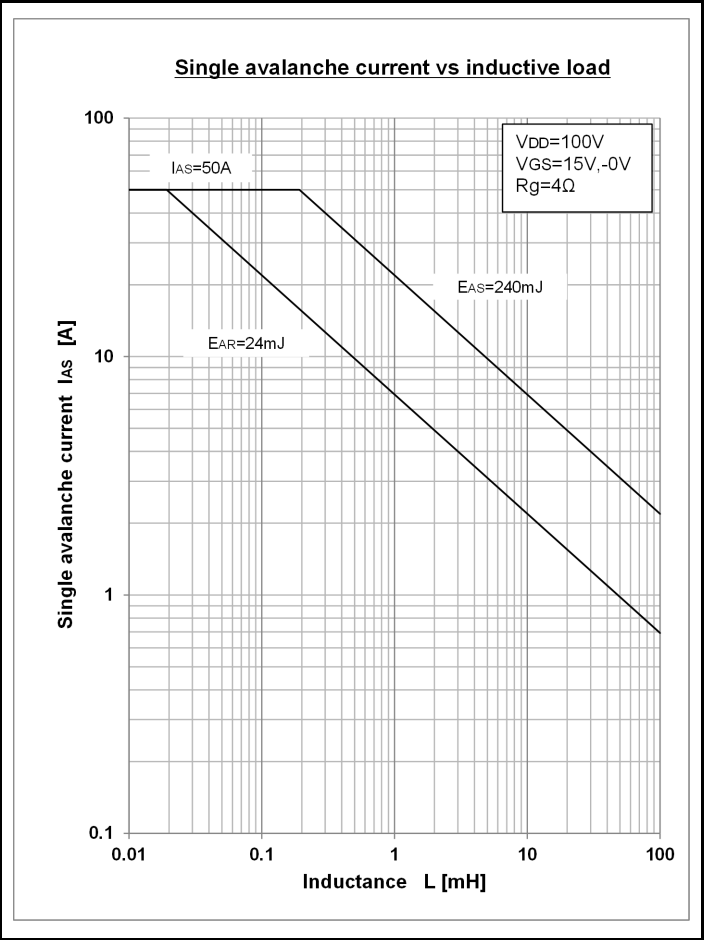
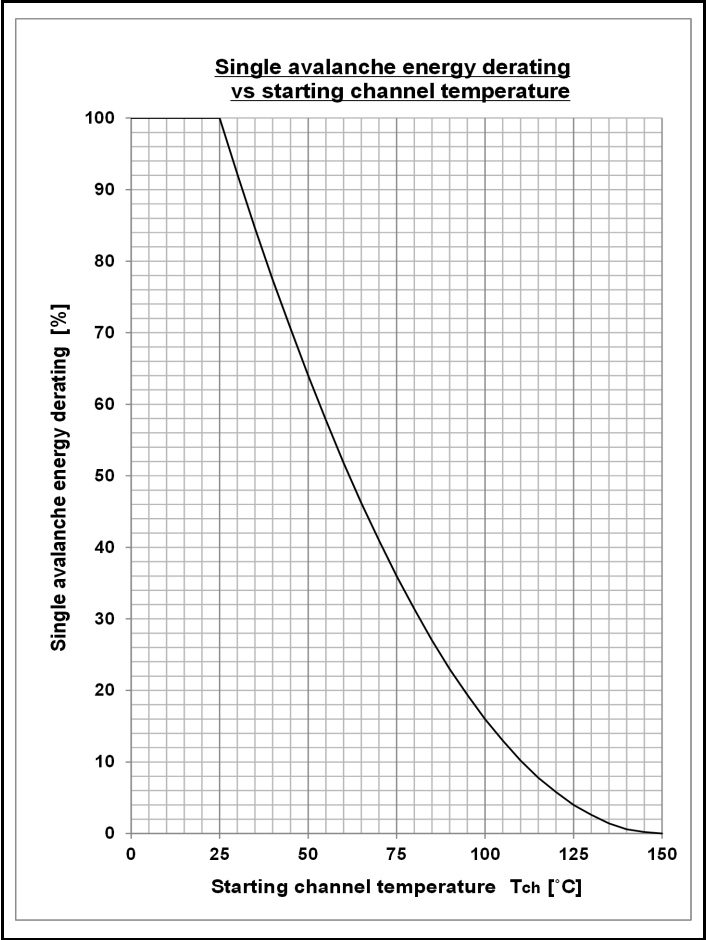


Static drain-source on-state resistance vs drain current



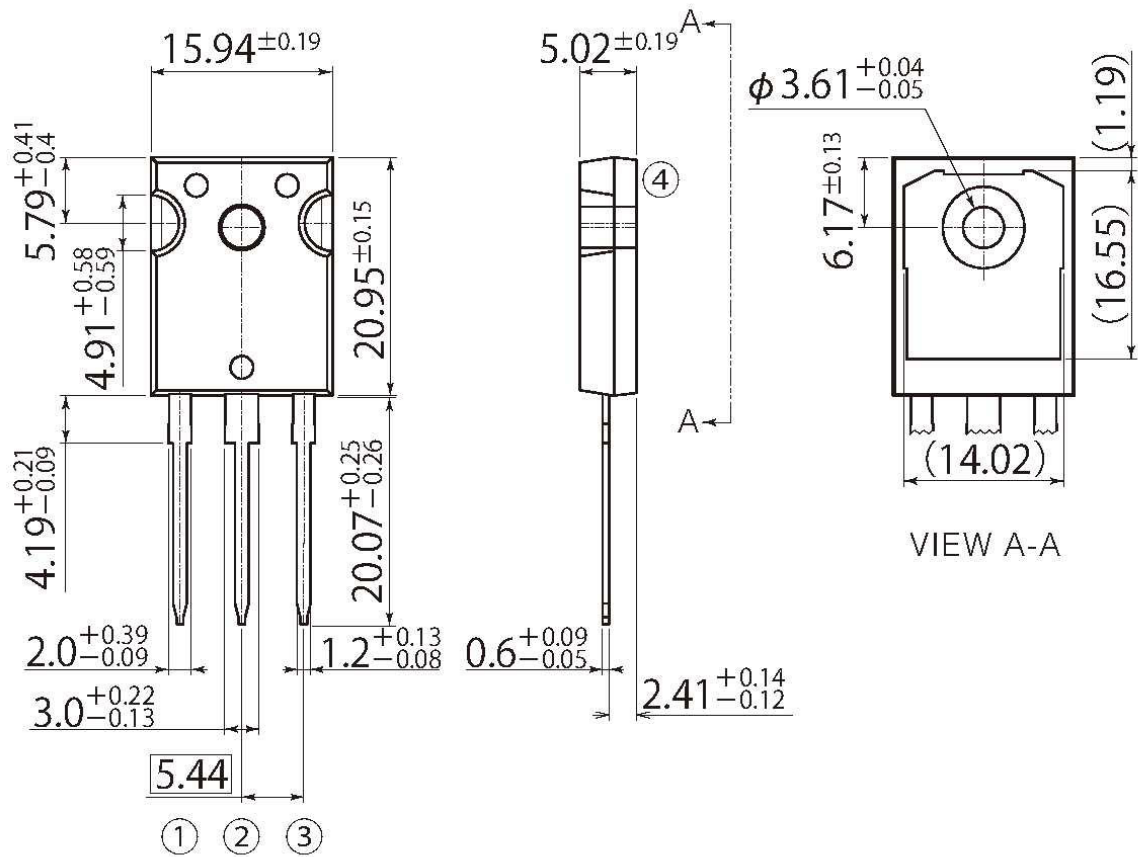






K8

JEDEC Code	TO-247AD
JEITA Code	—
House Name	GC



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